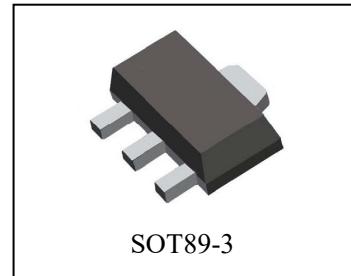


General Description

The 78HXXM family is monolithic fixed voltage regulator integrated circuit. They are suitable for applications requiring supply current up to 300mA.

The 78HXXM family is available in SOT89-3 package.



Features

- Output Current up to 300mA
- Fixed Output Voltage of 5V, 6V, 8V, 9V, 12V and 15V
- Thermal Overload Shutdown Protection
- Short Circuit Current Limiting

Package Information

Part NO.	Package Description	Package Marking	Package Option
78HXXM	SOT89-3	78HXXM SXXXX	1000/Reel

SXXXX:Lot NO.

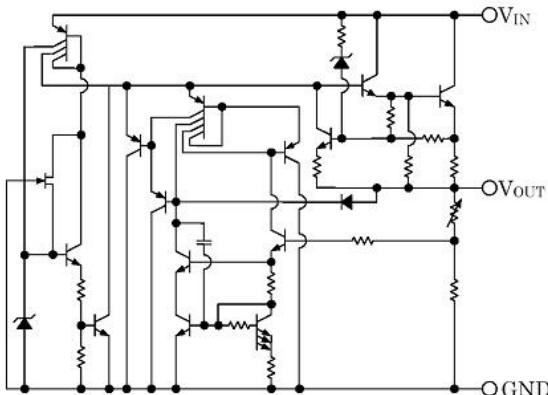
78HXXM:Part NO. (XX:Output Voltage)

XX(Output Voltage): 05(5.0V)/06(6.0V)/08(8.0V)/09(9.0V)/12(12V)/15(15V)

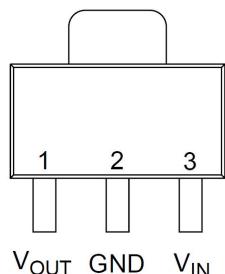
Applications

- Network Products
- Sound Card and Computer Motherboard
- Linear Regulator Source
- CD-ROM and DVD-ROM
- Controller

Functional Block Diagram



Pin Configuration



78HXXM(SOT89-3)

Pin Description

Pin Number	Pin Name	Function Description
1	V _{OUT}	Output pin
2	GND	Ground
3	V _{IN}	Input pin

Absolute Maximum Ratings (Operating temperature range applies, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Input Voltage	V _{IN}	30	V
Output Current	I _{OUT}	300	mA
Power Dissipation	P _D	550	mW
Operating Temperature Range	T _{opr}	-40~125	°C
Storage Temperature Range	T _{stg}	-55~150	°C

*1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

*2. It is guarantee by design, not 100% be tested.

78HXXM

Electrical Characteristics (C1=0.33uF, CO=0.1uF, unless otherwise specified) *1

78H05M (V_{IN}=10V, I_{OUT}=40mA)

Characteristics	Test conditions	Symbol	Min	Typ	Max	Unit
Output Voltage	T _j =25°C	V _{OUT}	4.80	5.00	5.20	V
	7V ≤ V _{IN} ≤ V _{MAX} I _{OUT} =1mA~300mA *2		4.75		5.25	
Load Regulation	T _j =25°C; I _{OUT} =1mA~300mA	Δ V _{OUT}		11	60	mV
	T _j =25°C; I _{OUT} =1mA~40mA			5.0	30	mV
Line Regulation	T _j =25°C; 7V ≤ V _{IN} ≤ 20V	Δ V _{OUT}		8	150	mV
	T _j =25°C; 8V ≤ V _{IN} ≤ 20V			6	100	mV
Quiescent Current		I _Q		2.0	5.5	mA
Quiescent Current Change	8V ≤ V _{IN} ≤ 20V	ΔI _Q			1.5	mA
	1mA ≤ V _{IN} ≤ 40mA				0.1	mA
Output Noise Voltage	10Hz ≤ f ≤ 100kHz	eN		40		μV
Temperature Coefficient of V _{OUT}	I _{OUT} =5mA	ΔVo/ΔT		-0.65		mV/°C
Ripple Rejection	8V ≤ V _{IN} ≤ 20V; f=120Hz; T _j =25°C	RR	41	80		dB
Dropout Voltage	T _j =25°C	V _D		1.7		V

78H06M (V_{IN}=12V, I_{OUT}=40mA)

Characteristics	Test conditions	Symbol	Min	Typ	Max	Unit
Output Voltage	T _j =25°C	V _{OUT}	5.76	6.00	6.24	V
	8.5V ≤ V _{IN} ≤ V _{MAX} I _{OUT} =1mA~300mA *2		5.7		6.3	
Load Regulation	T _j =25°C; I _{OUT} =1mA~300mA	Δ V _{OUT}		12.8	80	mV
	T _j =25°C; I _{OUT} =1mA~40mA			5.8	40	mV
Line Regulation	T _j =25°C; 8.5V ≤ V _{IN} ≤ 20V	Δ V _{OUT}		64	175	mV
	T _j =25°C; 9V ≤ V _{IN} ≤ 20V			54	125	mV
Quiescent Current		I _Q		2.0	5.5	mA
Quiescent Current Change	9V ≤ V _{IN} ≤ 20V	ΔI _Q			1.5	mA
	1mA ≤ V _{IN} ≤ 40mA				0.1	mA
Output Noise Voltage	10Hz ≤ f ≤ 100kHz	eN		49		μV
Temperature Coefficient of V _{OUT}	I _{OUT} =5mA	ΔVo/ΔT		0.75		mV/°C
Ripple Rejection	10V ≤ V _{IN} ≤ 20V; f=120Hz; T _j =25°C	RR	40	46		dB
Dropout Voltage	T _j =25°C	V _D		1.7		V

78HXXM

78H08M (V_{IN}=14V, I_{OUT}=40mA)

Characteristics	Test conditions	Symbol	Min	Typ	Max	Unit
Output Voltage	T _j =25°C	V _{OUT}	7.68	8.00	8.32	V
	10.5V ≤ V _{IN} ≤ V _{MAX} I _{OUT} =1mA~300mA *2		7.6		8.4	
Load Regulation	T _j =25°C; I _{OUT} =1mA~300mA	Δ V _{OUT}		15	80	mV
	T _j =25°C; I _{OUT} =1mA~40mA			8.0	40	mV
Line Regulation	T _j =25°C; 10.5V ≤ V _{IN} ≤ 23V	Δ V _{OUT}		10	175	mV
	T _j =25°C; 11V ≤ V _{IN} ≤ 23V			8	125	mV
Quiescent Current		I _Q		2.0	5.5	mA
Quiescent Current Change	11V ≤ V _{IN} ≤ 20V	ΔI _Q			1.5	mA
	1mA ≤ V _{IN} ≤ 40mA				0.1	mA
Output Noise Voltage	10Hz ≤ f ≤ 100kHz	eN		49		μV
Temperature Coefficient of V _{OUT}	I _{OUT} =5mA	ΔV _O /ΔT		0.75		mV/°C
Ripple Rejection	11V ≤ V _{IN} ≤ 23V; f=120Hz; T _j =25°C	RR	39	70		dB
Dropout Voltage	T _j =25°C	V _D		1.7		V

78H09M (V_{IN}=15V, I_{OUT}=40mA)

Characteristics	Test conditions	Symbol	Min	Typ	Max	Unit
Output Voltage	T _j =25°C	V _{OUT}	8.64	9.00	9.36	V
	11.5V ≤ V _{IN} ≤ V _{MAX} I _{OUT} =1mA~300mA *2		8.55		9.45	
Load Regulation	T _j =25°C; I _{OUT} =1mA~300mA	Δ V _{OUT}		15	90	mV
	T _j =25°C; I _{OUT} =1mA~40mA			8.0	45	mV
Line Regulation	T _j =25°C; 11.5V ≤ V _{IN} ≤ 24V	Δ V _{OUT}		15	200	mV
	T _j =25°C; 13V ≤ V _{IN} ≤ 24V			10	150	mV
Quiescent Current		I _Q		2.0	6.0	mA
Quiescent Current Change	13V ≤ V _{IN} ≤ 24V	ΔI _Q			1.5	mA
	1mA ≤ V _{IN} ≤ 40mA				0.1	mA
Output Noise Voltage	10Hz ≤ f ≤ 100kHz	eN		49		μV
Temperature Coefficient of V _{OUT}	I _{OUT} =5mA	ΔV _O /ΔT		0.75		mV/°C
Ripple Rejection	11V ≤ V _{IN} ≤ 23V; f=120Hz; T _j =25°C	RR	38	70		dB
Dropout Voltage	T _j =25°C	V _D		1.7		V

78HXXM

78H12M ($V_{IN}=18V$, $I_{OUT}=40mA$)

Characteristics	Test conditions	Symbol	Min	Typ	Max	Unit
Output Voltage	$T_j=25^\circ C$	V_{OUT}	11.52	12.00	12.48	V
	$14.5V \leq V_{IN} \leq V_{MAX}$ $I_{OUT}=1mA \sim 300mA$ *2		11.40		12.60	
Load Regulation	$T_j=25^\circ C; I_{OUT}=1mA \sim 300mA$	ΔV_{OUT}		20	150	mV
	$T_j=25^\circ C; I_{OUT}=1mA \sim 40mA$			8.0	75	mV
Line Regulation	$T_j=25^\circ C; 14.5V \leq V_{IN} \leq 27V$	ΔV_{OUT}		20	300	mV
	$T_j=25^\circ C; 16V \leq V_{IN} \leq 27V$			15	250	mV
Quiescent Current		I_Q		2.0	6.0	mA
Quiescent Current Change	$16V \leq V_{IN} \leq 27V$	ΔI_Q			1.5	mA
	$1mA \leq V_{IN} \leq 40mA$				0.1	mA
Output Noise Voltage	$10Hz \leq f \leq 100kHz$	e_N		80		μV
Temperature Coefficient of V_{OUT}	$I_{OUT}=5mA$	$\Delta V_{o/\Delta T}$		0.75		$mV/^\circ C$
Ripple Rejection	$11V \leq V_{IN} \leq 23V; f=120Hz; T_j=25^\circ C$	RR	37	70		dB
Dropout Voltage	$T_j=25^\circ C$	V_D		1.7		V

78H15M ($V_{IN}=21V$, $I_{OUT}=40mA$)

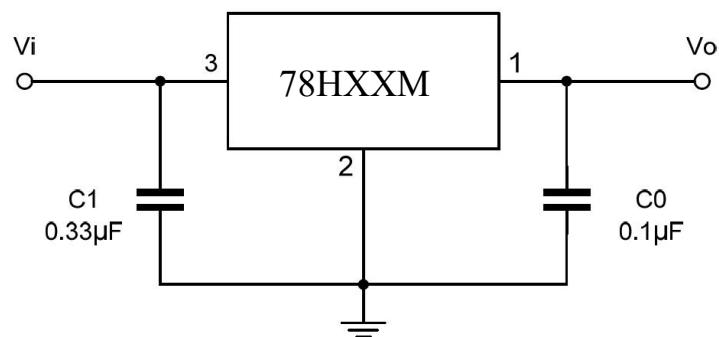
Characteristics	Test conditions	Symbol	Min	Typ	Max	Unit
Output Voltage	$T_j=25^\circ C$	V_{OUT}	14.40	15.00	15.60	V
	$17.5V \leq V_{IN} \leq V_{MAX}$ $I_{OUT}=1mA \sim 300mA$ *2		14.25		15.75	
Load Regulation	$T_j=25^\circ C; I_{OUT}=1mA \sim 300mA$	ΔV_{OUT}		30	160	mV
	$T_j=25^\circ C; I_{OUT}=1mA \sim 40mA$			10	80	mV
Line Regulation	$T_j=25^\circ C; 17.5V \leq V_{IN} \leq 30V$	ΔV_{OUT}		30	300	mV
	$T_j=25^\circ C; 20V \leq V_{IN} \leq 30V$			20	250	mV
Quiescent Current		I_Q		2.2	6.5	mA
Quiescent Current Change	$20V \leq V_{IN} \leq 30V$	ΔI_Q			1.5	mA
	$1mA \leq V_{IN} \leq 40mA$				0.1	mA
Output Noise Voltage	$10Hz \leq f \leq 100kHz$	e_N		90		μV
Temperature Coefficient of V_{OUT}	$I_{OUT}=5mA$	$\Delta V_{o/\Delta T}$		0.75		$mV/^\circ C$
Ripple Rejection	$11V \leq V_{IN} \leq 23V; f=120Hz; T_j=25^\circ C$	RR	34	70		dB
Dropout Voltage	$T_j=25^\circ C$	V_D		1.7		V

78HXXM

*1. The Maximum steady state usable output current are dependent on input voltage, heat sinking, lead length of the package and copper pattern of PCB. The data above represent pulse test conditions with junction temperatures specified at the initiation of test.

*2. Power dissipation<0.5W

Typical Application



*1. To specify an output voltage, substitute voltage value for "XX".

*2. Bypass capacitors are recommended for optimum stability and transient response and should be located as close as possible to the regulators.

Characteristics Curves

Fig.7 78H05A Quiescent Current vs. Input Voltage ($I_{OUT}=0mA, T_J=25^{\circ}C$)

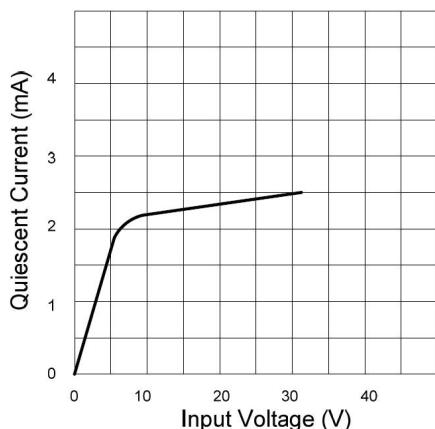


Fig.8 Peak Output Current vs Dropout Voltage Difference

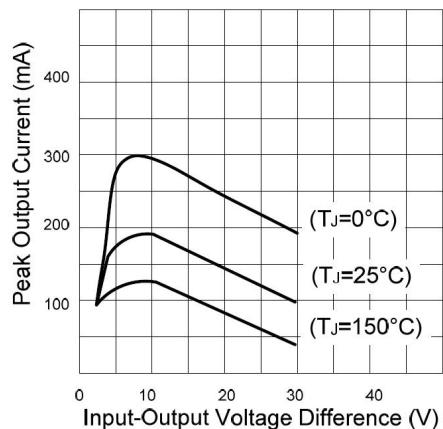


Fig.1 Ambient Temperature vs. Power Dissipation

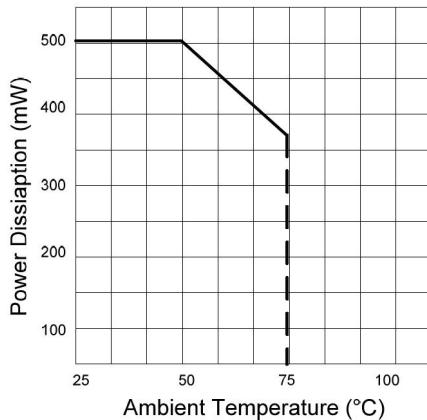


Fig.2 78H05A Output Voltage vs.Ambient Temperature

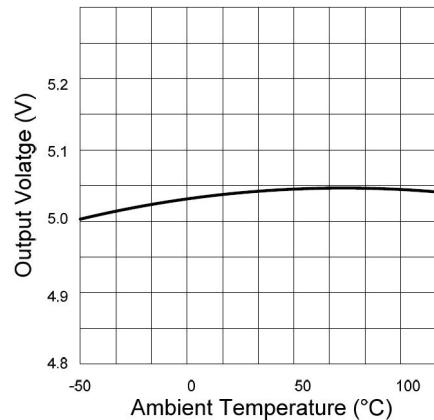


Fig.3 78H08A Output Volatge vs. Ambient Temperature

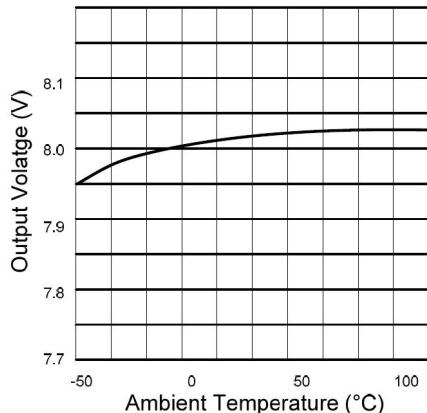


Fig.4 Output Characteristics ($I_{out}=0mA, T_j=25^{\circ}C$)

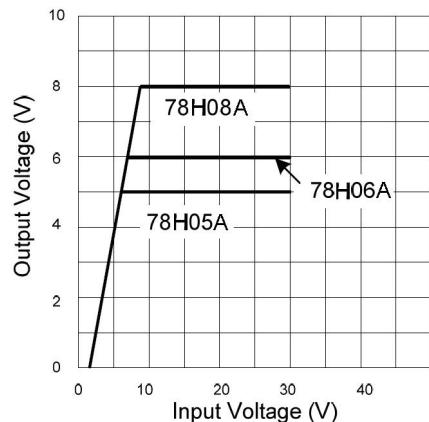


Fig.5 78H05A Dropout Characteristics ($T_j=25^{\circ}C$)

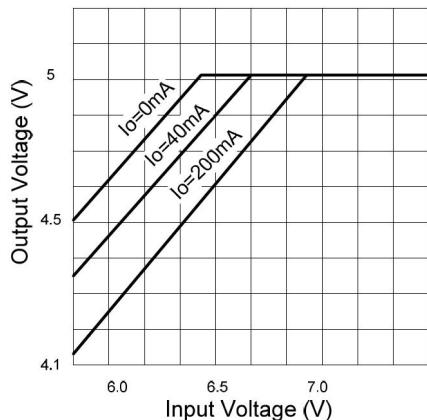
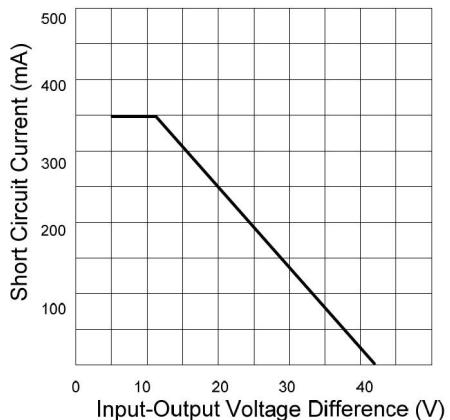
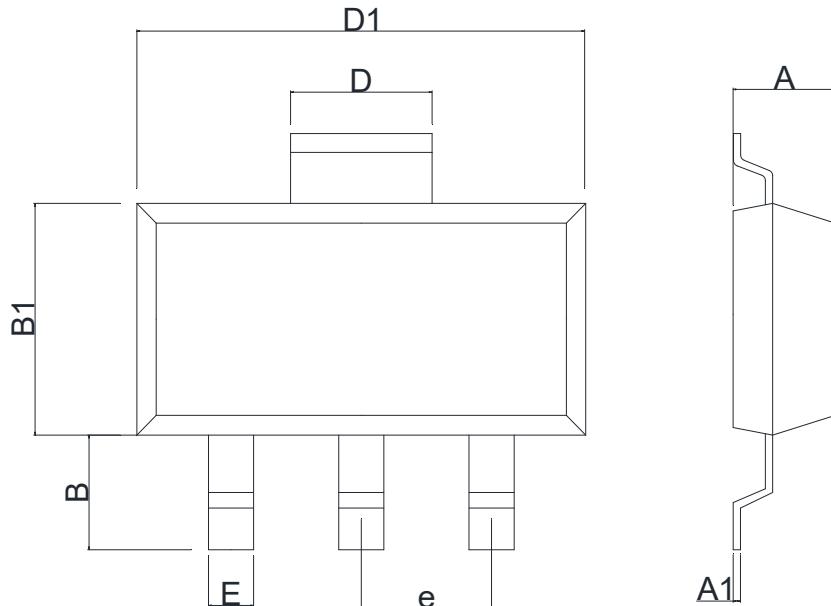


Fig.6 Short Circuit Output Current ($T_j=25^{\circ}C$)



Outline Dimensions

SOT89-3		Unit: mm			
Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
A	1.450	1.550	0.057	0.061	
A1	0.390	0.410	0.015	0.016	
B	0.950	1.050	0.037	0.041	
B1	2.350	2.550	0.092	0.100	
E	0.350	0.450	0.013	0.017	
D1	4.400	4.600	0.173	0.181	
D	1.550 REF		0.061 REF		
e	1.500 (BSC)		0.059 (BSC)		



The diagram shows the physical dimensions of the SOT89-3 package. It features a central rectangular body with a lead frame. Key dimensions are labeled: D1 (width) is 4.400 to 4.600 mm; B1 (length) is 2.350 to 2.550 mm; E (height) is 0.350 to 0.450 mm; A (top thickness) is 1.450 to 1.550 mm; A1 (lead thickness) is 0.390 to 0.410 mm; B (lead spacing) is 0.950 to 1.050 mm; and e (lead thickness at the base) is 1.500 mm (BSC). The top view also shows internal features D and d.

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